



# Acceleratori - RF @ Sapienza/INFN-Roma1

Luigi Palumbo Sapienza&INFN-Roma1

Team

L. Palumbo (PO), E. Chiadroni (PA), M. Migliorati (PA), A. Mostacci (PA), M. Petrarca (PA),
L. Ficcadenti (INFN-Roma1) (+ L. Faillace now at LNF & B. Spataro)
& 4 PhD students (L. Giuliano, F. Bosco, M. Carillo, D. De Arcangelis).

## Sapienza-INFN/Roma1 Accelerator Activity at glance

Participation in R&D effort @LNF (SPARC/Eupraxia@INFN-LNF - all)

Design of X-band hybrid photoinjector (Mostacci, Faillace, Ficcadenti, Spataro)

C-band cavity design for SPARC&ELI (mechanical workshop in SBAI + INF-Roma1) (all)

Design of compac hybrid high C- band gradient injectors for radiation sources (FEL, Compton) & beam dynamics studies (Migliorati, Mostacci, Faillace, Bosco, Carillo)

Novel medical linear accelerators for FLASH therapy (Migliorati, Mostacci, Faillace, Giuliano)

Collective effects and impedance budget for FCC-ee (M. Migliorati) Transverse mode coupling instability for SuperKEKB (International Task Force, M.Migliorati) THz Laser Laboratory (M. Petrarca)

#### Collaborations

**Main Activities** 

**<u>Research institutes</u>:** INFN, UCLA, CERN, LBNL, KEK Industries: SIT

Synergies

**<u>EU projects</u>: EuroFel, ELI, Eucard<sup>2</sup>, EuroNNAc, EupraXia, FCC-IS, XLS-CompactLight** 

#### **RF - ACCELERATORS- LABORATORY (Resp. Andrea Mostacci)**

#### Vector Network Analyzers (VNA) and SPectrum Analyzers (SPA)



Fieldfox VNA/SPA - 14GHz



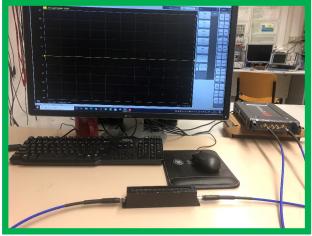
USB VNA - 20GHz



PNA VNA - 20GHz



VNA - 6GHz

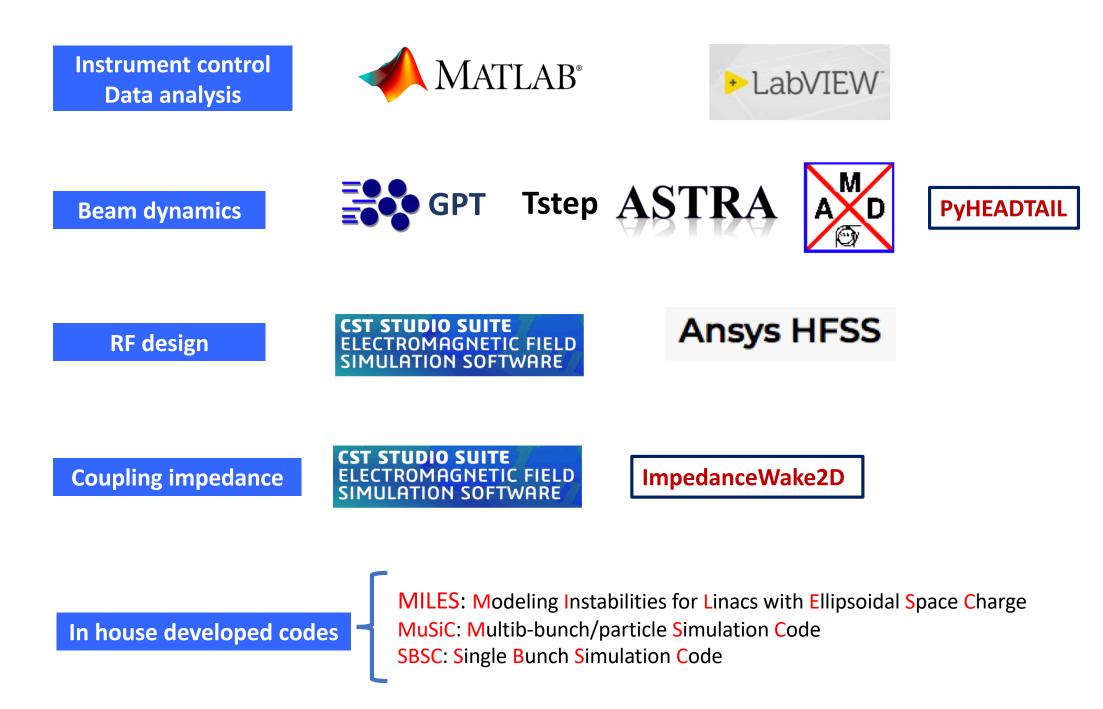


USB VNA - 6GHz

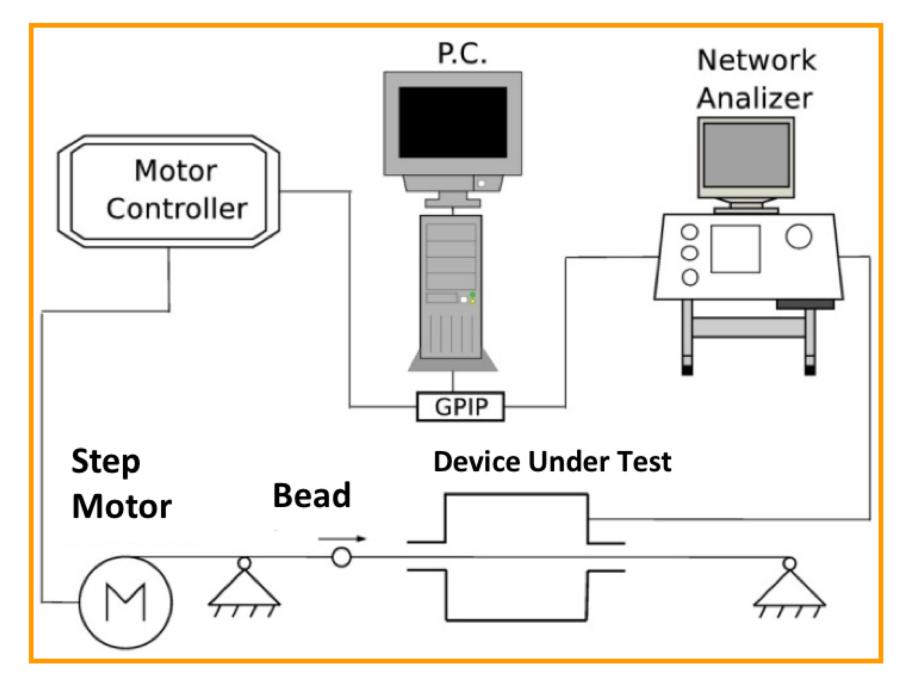


SPA - 3GHz Signal generator – 3GHz

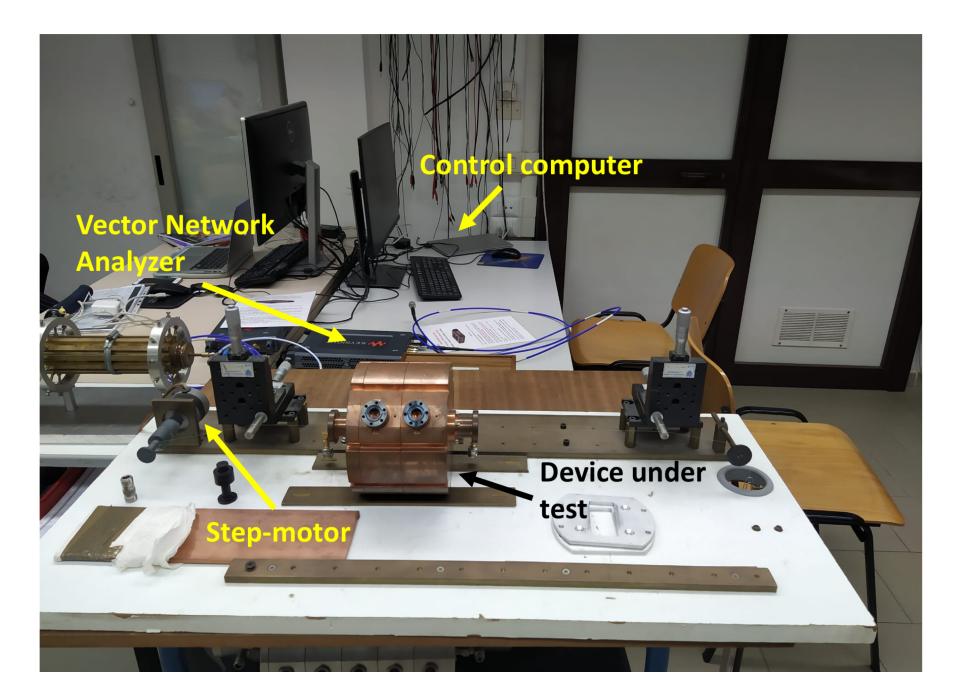
#### **Available Software**



#### **1**<sup>st</sup> instrumentation : Bead pull bench measurements



#### **Bead pull bench measurements: implementation**

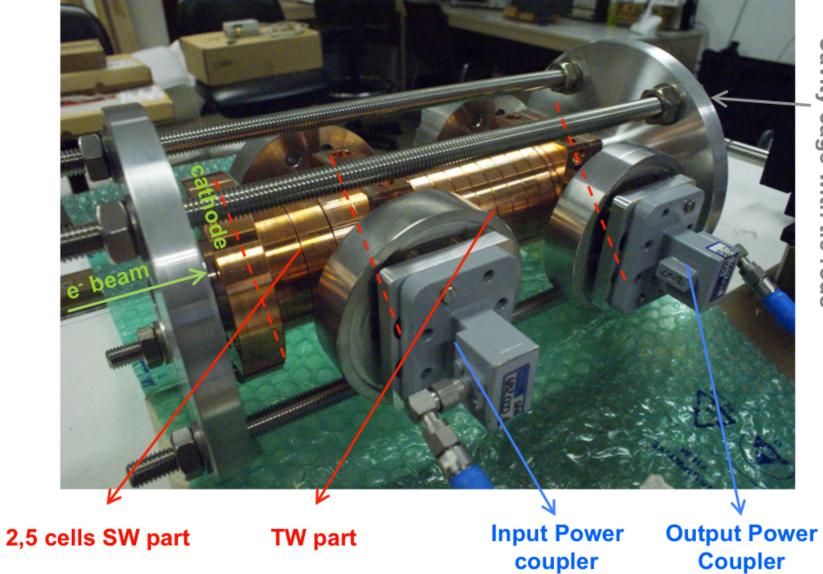


# **X-BAND HYBRID ELECTRON GUN (11.424 GHz)**



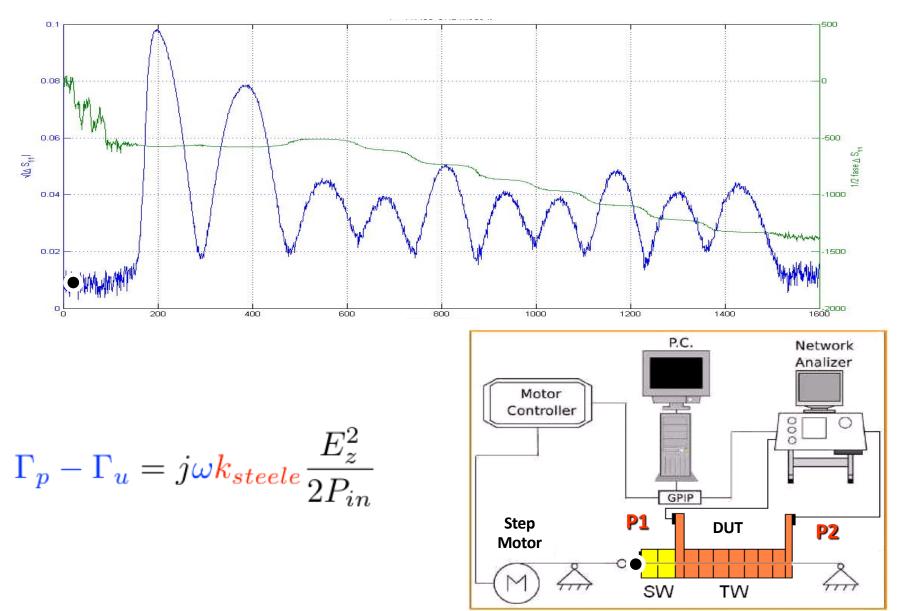






Cavity cage with tie rods

## **BEAD PULL MEASUREMENTS**



# **TUNING OF C BAND TW STRUCTURE (coll. LNF)**

Goal

Accelerating field flatness along the cells with proper phase advance per cell.

1. measure the complex field distribution In at working frequency (bead-pull);

2. calculate the local reflection coefficients Γn of each regular cell;

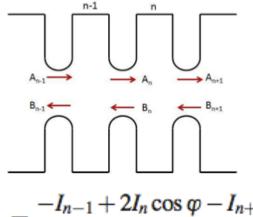
3. predict the deformation to be applied to the cells;

4. tune the cells looking at the variation of the modulus of the global reflection coefficient  $|\Delta\Gamma$ global|;

5. repeat such procedure until the  $\Gamma n$  is smaller of the desired value (~| $\Gamma n$ | < 0.005)

D. Alesini et al., Tuning procedure for travelling wave structures and its application to the C-Band cavities for SPARC photo injector energy upgrade, Journal of Instrumentation, 2013.

J. Shi, A. Grudiev, A. Olyunin, Tuning of CLIC accelerating structure prototypes at CERN, CERN, 2010



$$\Gamma_n = \frac{-I_{n-1} + 2I_n \cos \varphi - I_{n+1}}{I_{n-1} - I_n \exp\left(-j\varphi\right)}.$$

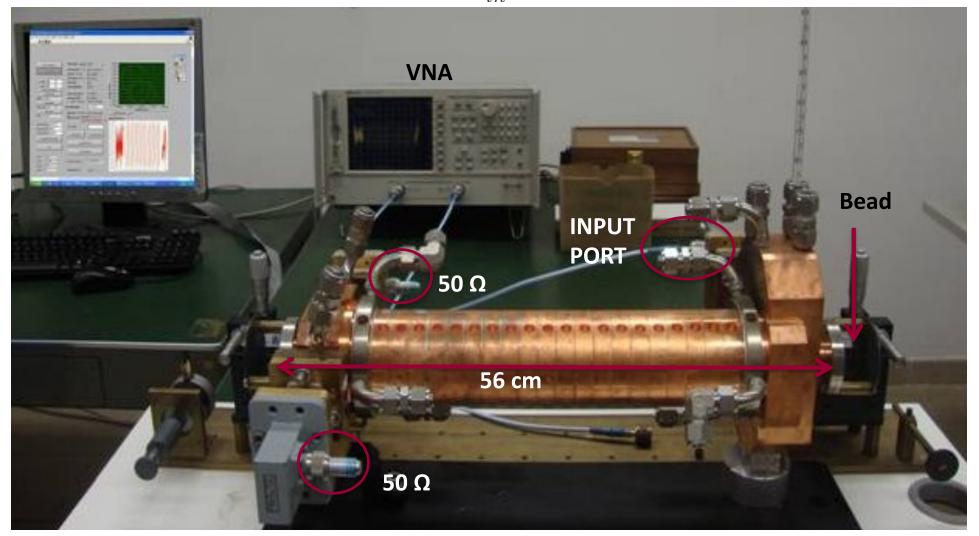
$$\Gamma_n = j Q_{0,n}' \frac{\Delta f_n}{f_{RF}},$$

 $\left|\Delta\Gamma_{\text{global}}\right| = e^{-2\alpha(n)} \left|\Delta\Gamma_{n}\right|$ 

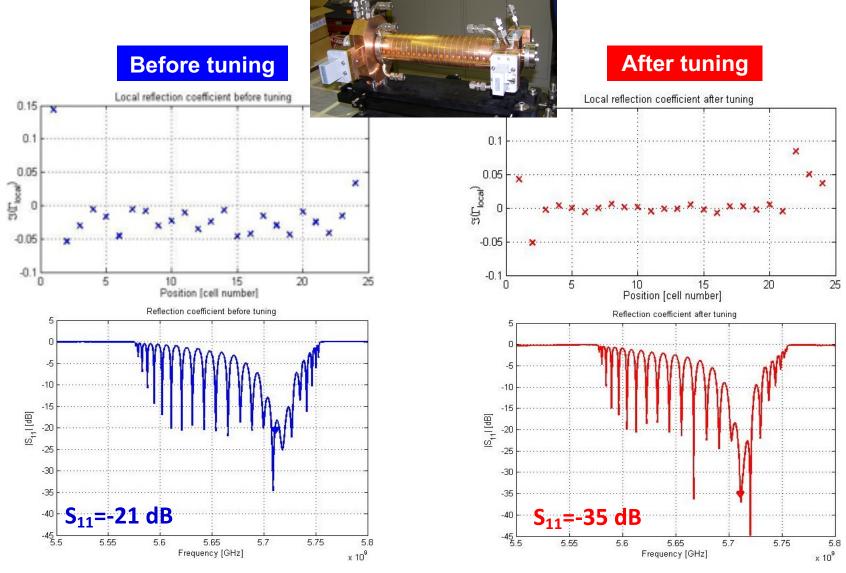
## **BEAD PULL MEASUREMENT SET-UP**

#### **Steele formula**

$$\Gamma_p - \Gamma_u = j\omega k_{bead} \frac{E_z^2}{2P_{in}}$$

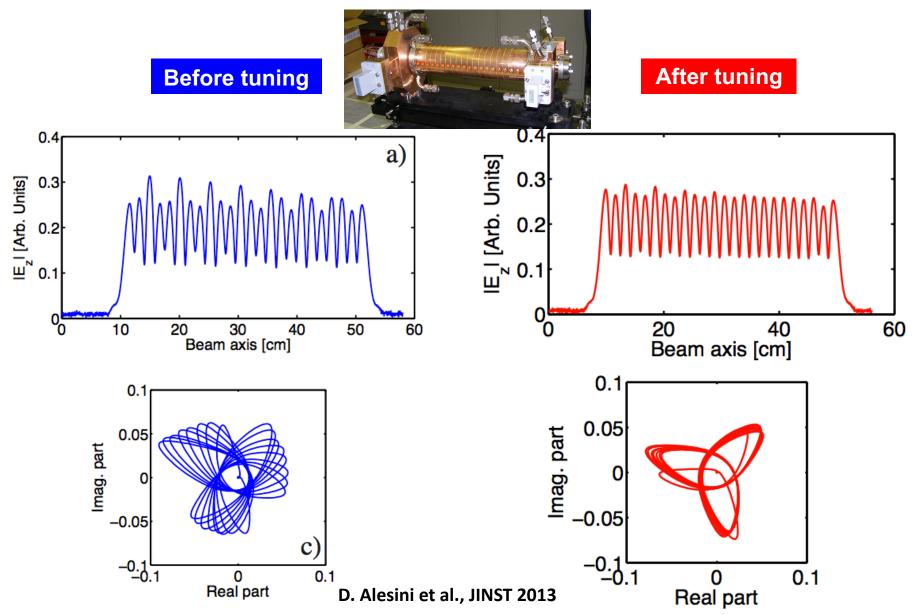


## **REFLECTION MEASUREMENTS**

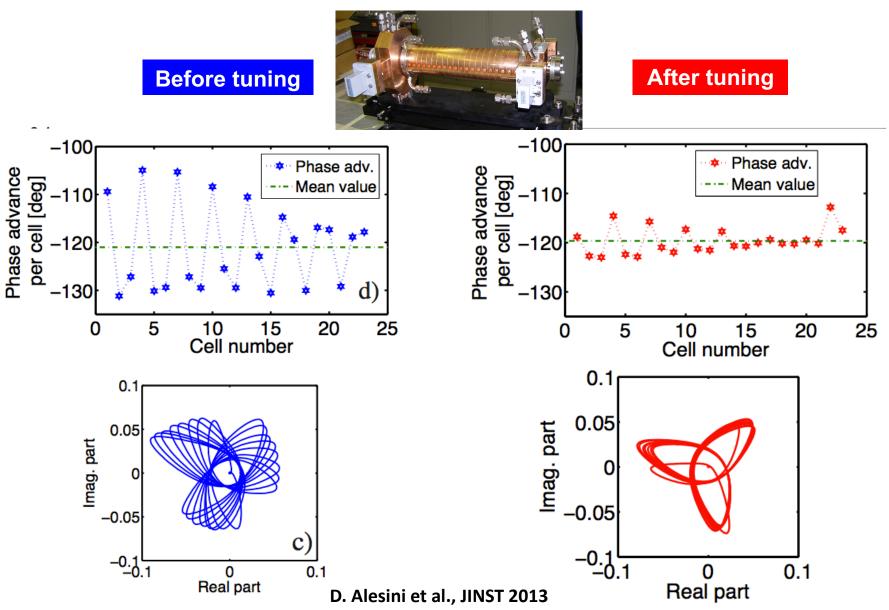


D. Alesini et al., JINST 2013

## FIELD MEASUREMENTS



## **FIELD MEASUREMENTS**

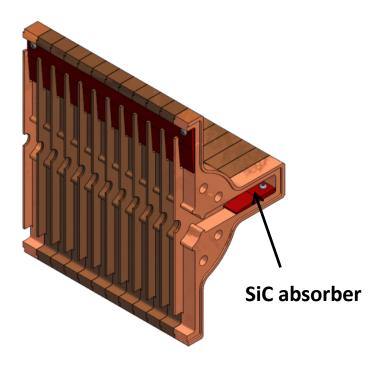


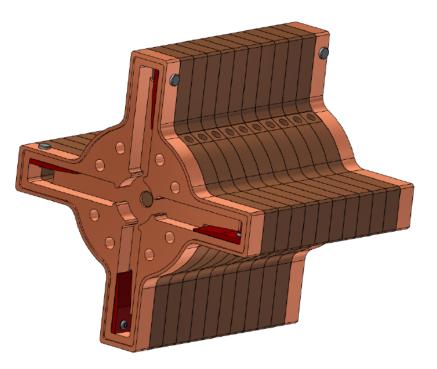
# DAMPED STRUCTURE SiC ABSORBERS (ELI)

Each cell of the structure has four waveguides that allows the excited HOMs to propagate and dissipate into silicon-carbide (SiC) RF loads.

The SiC tiles have been optimized to avoid reflections and are integrated into the structure.

In each stack of 12 cells there are four SiC long absorbers, each stack is brazed and all stacks are finally assembled and brazed with the input and output couplers.



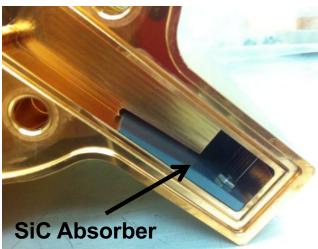


# **DAMPED STRUCTURE PROTOTYPES**

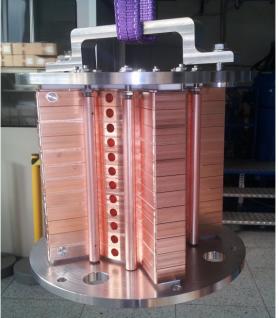
Intense activity of prototyping to verify both feasibility of copper cells machining and effectiveness of brazing process.

**Mechanical prototype: full scale** device, without precise internal dimensions and with SiC absorbers, to test the brazing process, structure deformations and vacuum leaks.

**RF prototype:** device with reduced number of cells with precise internal dimensions with tuners and SiC absorbers, to test the RF properties of the structure at low and high power.







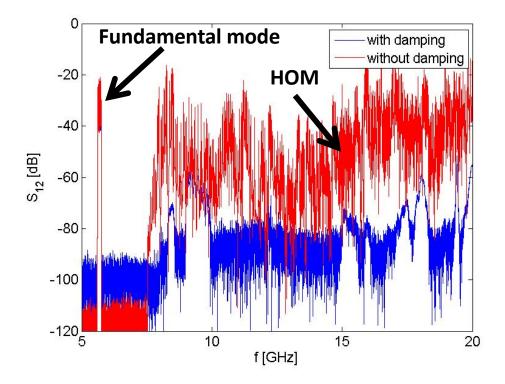
R&D program in close collaboration with Italian Companies (COMEB, CERINCO, ANDALO GIANNI, TSC)

## **RF TEST OF 12 CELLS PROTOTYPE**

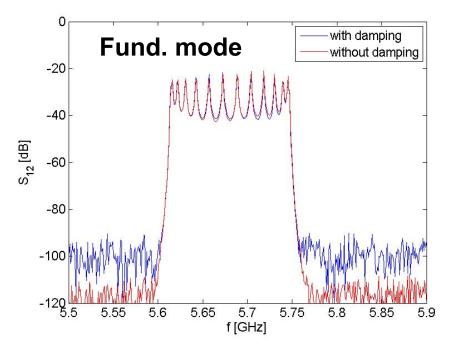
Low power RF test in the 12 cells module with and without the SiC absorbers (antenna coupling).

No dumpers: HOM Q factor of few 1000s

With dumpers: HOM hardly measurable.



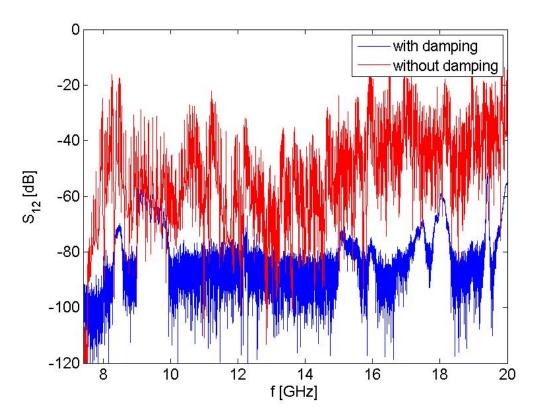




# **RF TEST OF 12 CELLS PROTOTYPE**

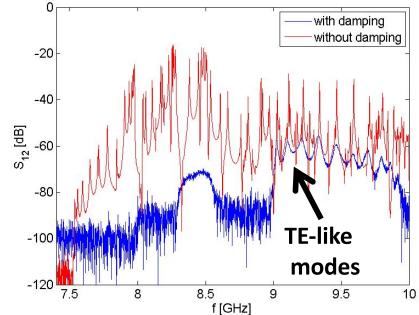
Low power RF test in the 12 cells module with and without the SiC absorbers (antenna coupling).

**TE modes:** Q factor of few hundreds.



Negligible transverse impedance.





# **ELECTRON LINAC FLASH RADIOTHERAPY**

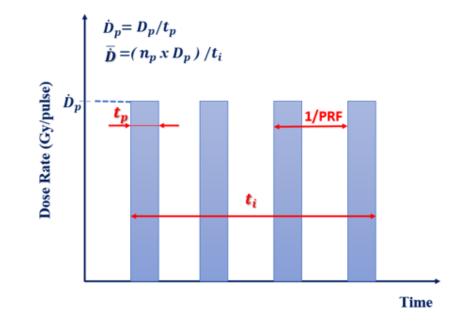
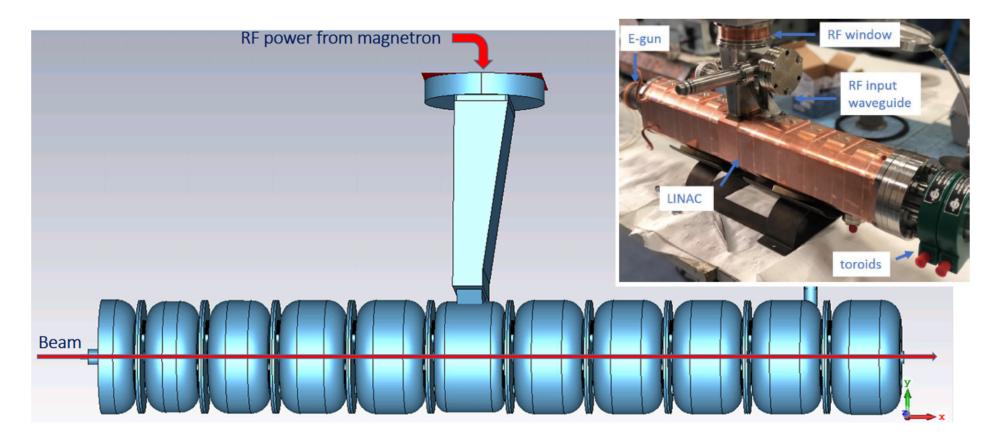
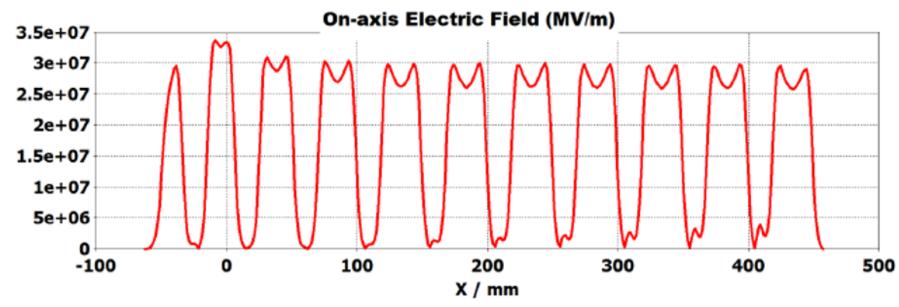


Table 1: Main FLASH parameters for the irradiations.

Parameter	Description	Value
PRF	Pulse repetition frequency	> 100  Hz
$t_p$	Pulse width	0.1-4.0 μs
$\frac{\mathbf{t}_i}{\dot{D}}$	Total irradiation time	< 100 ms
$\overline{\dot{D}}$	Time-averaged dose rate	$> 100 { m ~Gy/s}$
$\dot{D_p}$	Dose-rate in a single pulse	$> 10^6 \text{ Gy/s}$
$D_p$	Dose in a single pulse	> 1 Gy





#### PROGETTO LINAC-FLASH 7 MeV – realizzato dalla SIT – primo esemplare al CURIE Parigi



Table 2: Main characteristics of the EF4000		
Characteristics EF4000	Value	
Output energy	5 - 7 MeV	
Pulse repetition frequency	1 - 250 Hz	
Pulse width	0.5 - 4 µs	
Maximum peak beam current	120 mA	
Dose rate per pulse	$> 10^6 \text{ Gy/s}$	
Mean Dose rate	1000 Gy/s	
Max Dose per pulse	30 Gy in a surface of $\varnothing$ 10 mm	

PHYSICAL REVIEW ACCELERATORS AND BEAMS 24, 050102 (2021)

Compact S-band linear accelerator system for ultrafast, ultrahigh dose-rate radiotherapy

L. Faillace,<sup>1,6,\*</sup> S. Barone,<sup>2</sup> G. Battistoni,<sup>3</sup> M. Di Francesco,<sup>2</sup> G. Felici,<sup>2</sup> L. Ficcadenti,<sup>4</sup> G. Franciosini,<sup>4,5</sup> F. Galante,<sup>2</sup> L. Giuliano,<sup>1,4</sup> L. Grasso,<sup>2</sup> A. Mostacci,<sup>1,4</sup> S. Muraro,<sup>3</sup> M. Pacitti,<sup>2</sup> L. Palumbo,<sup>1,4</sup> V. Patera,<sup>1,4</sup> and M. Migliorati,<sup>1,4</sup>

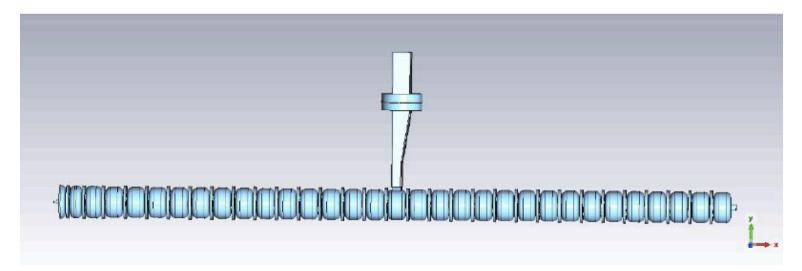
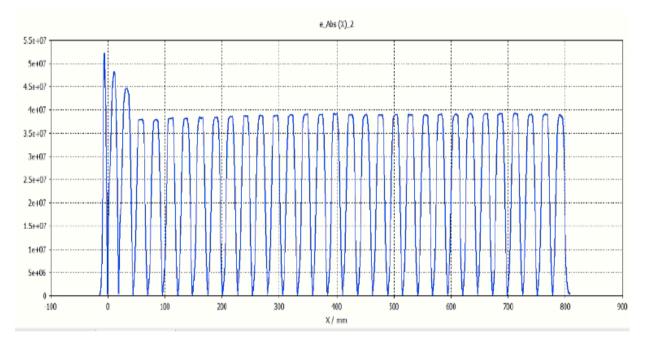


Fig. 1: Modello 3D da CST del linac in banda C composto da 32 celle acceleranti



 simulazione con la guida d'onda e la RF window per la sintonizzazione del linac completo;





# VHEE Very High Energy Electrons (50-250 MeV) for deep tumors

The discovery of FLASH effect and the technology innovation in accelerator physics are freeing the VHEE RT from the limbo.



the treatment of superficial tumours and thus limiting their clinical applicability.

The investment (man power, funding, infrastructure) in the field are mainly driven by the fundamental research (but also companies are active) and a clear example is a new initiative is starting at CERN/SLAC

#### **VHEE & the FRIDA project: a CSN5 call**

Goal of FRIDA is aCSN5 interdisciplinary call proposal addressing all the crucial areas related with FLASH therapy. 4 work-packages ✓ mechanism modelling & rad-bio experiments;

- ✓ beam delivery techniques ;
- Detectors for beam monitoring;
- ✓ treatment planning development

- Explore the time scales at which the FLASH effect occurs
- Develop compact, high intensity sources and delivery solutions for EBRT with e and p
- Explore novel detection strategies both for dosimetry and beam monitoring applications
- Explore clinical potential of FLASH EBRT



# Personnel - Sections



A community of 80 researchers distributed in 7 INFN sections & Labs: CT, LNS, Milano, Pisa, Roma1, TIFPA, Torino.

- CT: Amato, Bartolotta, Borgese, D'Oca, Italiano, Marrale, Romano, Tomarchio (3.8 FTE)
- LNS: Bravatà, Calvaruso, Cammarata, Catalano, Cirrone, Cuttone, Forte, Guarrera, Mauro, Ficarra, Milluzzo, Minafra, Petringa, Russo, Sorbello, Torrisi (FTE: 4.7)
- Milano: Bortolussi Bacci Dong Drebot Giove Mattei Muraro Massa -Mattei - Mettiver - Russo - Sarnu - Serafini (2 FTE)
- Pisa: Belcari, Bisogni, Costa, Del Sarto, Di Martino, Gizzi, Kraan, Labate, Marasciulli, Morrocchi, Paiar, Rosso, Sportelli, Strettoi, Ursino, Vannini, Zanacchi (2.8 FTE)
- Roma1: Faillace, Ficcadenti, Franciosini, Giuliano, Marafini, Migliorati, Mostacci, Palumbo, Patera, Sarti, Schiavi, Toppi, Traini, Trigilio (2.5 FTE)
- TIFPA: Attili, Bellinzona, Bisio, Boscolo, Cordoni, Croci, Fuss, Manghi, La Tessa, Scifoni, Schwarz, Tommasino (4.0 FTE)
- Torino : Abujami, Aprà, Cirio, Martì Villarreal, Monti, Picollo, Vignati (4.3 FTE)

#### **GRUPPO LAVORO SAPIENZA-INFN, FLASH-VHEE-RT**

#### PRECEDENTI: INCONTRO RETTRICE POLIMENI CON PRESIDENTE ZOCCOLI INCONTRO CON PRORETTICE ALLA RICERCA SARTO E VICEPRESIDENTE BETTONI + riunioni separate con la Rettrice e con il Presidente INFN

SAPIENZA				
Cardinale Vincenzo				
Cenci Giovanni				
Giuliano Lucia	(& INFN)			
Marampon Francesco				
Migliorati Mauro	(& INFN)			
Mostacci Andrea	(& INFN)			
Patera Vincenzo	(& INFN)			
Palumbo Luigi	(& INFN)			
Sarti Alessio	(& INFN)			
Tombolini Vincenzo				

#### <u>INFN</u>

Alesini David Bisogni Maria Giuseppina Cuttone Giacomo (Resp. INFN for Life Science) Faillace Luigi Gallo Alessandro Pablo Cirrone Torrisi Giuseppe

#### **GOAL: STUDIO FATTIBILITA' ENTRO 2021**